Presenter Index

Version: 06/15/23

Canyon III	Wednesday	05:20 PM	InP Nano-Ridge Engineering for III-V device integration on silicon substrates
Canyon I	Tuesday	09:20 PM	XRD analysis of relaxation of non-biaxial strain at the semipolar interface in AlGaN grown via heteroepitaxial FACELO
Canyon I	Tuesday	08:00 PM	Crack suppression of high Al-mole-fraction AlGaN layers on patterned GaN substrates for ultraviolet laser diodes
Canyon I	Tuesday	11:40 AM	Strain Accumulation and Relaxation in AlN Film on Si (111) Substrate: A Consideration on Crack Formation in Epitaxial Growth of Ultrawide-Bandgap Semiconductor Films
Canyon I	Tuesday	04:40 PM	RF-MBE Growth of GaN on ScAIMgO4 Substrate
Canyon II & IV	Thursday	08:30 AM	It's a surprise!
Canyon II & IV	Thursday	09:00 AM	It's a surprise!
Canyon III	Wednesday	03:20 PM	Imaging dislocation networks formed by using defect filter layers in the growth of GaSb on GaAs.
Canyon III	Tuesday	11:30 AM	(Invited) Heterostructuring by Mechanochemical Reshuffling of Layered 2D - Metal Chalcogenides.
Aster	Monday	03:30 PM	(Invited) Room-Temperature Growth, Ferroelastic Domains and Optoelectronic Properties of Halide Perovskite CH3NH3PbX3 (X = I, Br and Cl) and CsPbBr3 Single Crystals
Arizona Foyer	Monday	05:30 PM	(Poster) Growth of Single Crystal Fibers for Laser Applications
Canyon II & IV	Tuesday	05:30 PM	Applying Kinetic Monte Carlo Modeling to Irregular Rod Eutectic Systems
Canyon III	Wednesday	01:30 PM	(Invited) Freestanding semiconductor nanomembranes: from materials to devices
Canyon III	Wednesday	03:00 PM	Growth of AllnP by Dynamic-Hydride Vapor Phase Epitaxy for Optoelectronic Devices
Canyon I	Friday	09:20 AM	Recent advances in epitaxial growth, in-situ etch, and regrowth of beta-Ga2O3 films using MOVPE
Canyon III	Thursday	10:30 AM	(Invited) Selective Area Growth of N-polar GaN Nanostructures for Core-Shell Optoelectronic Devices
Arizona Foyer	Monday	05:30 PM	(Poster) Magnetization - induced spin current flip in (4R)FeO3 single crystal (R- Rare-earth)
Arizona Foyer	Monday	05:30 PM	(Poster) Influence of Eu $3+$ doped on the spin reorientation in the imperfect antiferromagnetic system of Sm $1-x$ Eu $x$ FeO $3$ ( $x = 0.25, 0.5$ and $0.75$ ) single crystals
Canyon II & IV	Wednesday	05:10 PM	Investigation of Synthesis Growth and Characterization of Single Crystal of 2-Methyl Benzimidazole and 4-Aminobenzoic Acid for Photonic Applications
	Canyon I Canyon I Canyon I Canyon II & IV Canyon III & IV Canyon III Aster Arizona Foyer Canyon III Canyon III Canyon III Arizona III Canyon III	Canyon I Tuesday Canyon I Tuesday Canyon I Tuesday Canyon I Tuesday Canyon II & IV Thursday Canyon II & IV Thursday Canyon III Wednesday Canyon III Tuesday Aster Monday Arizona Foyer Monday Canyon III Wednesday Canyon III Wednesday Canyon III Tuesday Tuesday Tuesday Arizona Foyer Monday Canyon III Tuesday Monday	Canyon I         Tuesday         09:20 PM           Canyon I         Tuesday         08:00 PM           Canyon I         Tuesday         11:40 AM           Canyon II & IV         Tuesday         04:40 PM           Canyon II & IV         Thursday         08:30 AM           Canyon III         Wednesday         09:00 AM           Canyon III         Tuesday         11:30 AM           Aster         Monday         03:30 PM           Arizona Foyer         Monday         05:30 PM           Canyon III & IV         Tuesday         05:30 PM           Canyon III         Wednesday         03:00 PM           Canyon III         Wednesday         03:00 PM           Canyon III         Thursday         03:00 PM           Canyon III         Thursday         10:30 AM           Arizona Foyer         Monday         05:30 PM           Arizona Foyer         Monday         05:30 PM

Yunfei Chang	Aster	Friday	11:00 AM	(Invited) Enhanced piezoelectric properties and superior unipolar fatigue resistance in textured Pb(Mg1/3Nb2/3)O3-PbZrO3-PbTiO3 textured ceramics
Eric Chason	Canyon II & IV	Tuesday	03:30 PM	(Invited) Relating stress in thin films to the processes of crystal growth
Zeyu Chen	Canyon I	Thursday	11:30 AM	Analysis of strain due to High Energy Ion Implantation by Synchrotron X-ray Topography
Qianyu Cheng	Canyon I	Wednesday	03:20 PM	Effective Penetration Depth Analysis of Dislocations Lying on the Basal Plane in Grazing Incidence Synchrotron X-ray Topographs of 4H-SiC Wafers
Deep Choudhari	Canyon III	Thursday	05:00 PM	(Invited) Investigation of in-liquid ordering mediated transformations in Al-Sc via ab initio molecular dynamics and unsupervised learning
Lu-Chung Chuang	Canyon I	Wednesday	04:30 PM	(Invited) In situ observation of growth behavior of small-angle grain boundaries in multicrystalline silicon during directional solidification
Duck Young Chung	Canyon II & IV	Friday	08:30 AM	Physical Properties of CsPbBr3 Crystal and Bridgman Crystal Growth
Cristian Ciobanu	Canyon II & IV	Tuesday	10:30 AM	(Invited) Growth of highly oriented, high-entropy transition metal disulfide (VNbMoTaW)Sx thin films
Sandy Cochran	Aster	Thursday	02:30 PM	(Invited) Motivation, Challenges and Potential Solutions in Characterisation of Bulk Piezoelectric Crystal Materials
Ioana Cozmuta	Canyon I	Monday	02:20 PM	An Al predictive platform for microgravity innovation
Ajisha D S	Arizona Foyer	Monday	05:30 PM	(Poster) Nucleation parameters, thermal and mechanical behavior of nonlinear optical potassium hydrogen oxalate trihydroxyborate single crystal
Jennifer DeMell	Canyon III	Tuesday	03:00 PM	(Invited) Spintronic Quantum Phase Transition in a Graphene/Pb0.24Sn0.76Te Topological Heterostructure with Giant Rashba Spin Texture
Pooja Devi	Arizona Foyer	Monday	05:30 PM	(Poster) Growth and characterization of co-crystal of vanillin and hexamethylenetetramine for NLO application
Alix Deymier	Aster	Tuesday	04:30 PM	Thermodynamic effects of stress on the crystal growth of apatite in aqueous environments
Jacob Dooley	Canyon I	Tuesday	03:50 PM	On the solubility of boron nitride in supercritical ammonia-sodium solutions
Wei Du	Canyon I	Thursday	04:00 PM	(Invited) Development of SiGeSn Technology for Monolithic Infrared Silicon Photonics
Russell Dupuis	Canyon I	Tuesday	08:20 PM	Nitrogen-Implanted Floating Guard Rings as Edge Termination for kV-Class Vertical GaN PIN Rectifiers for Breakdown Voltage Improvement and Premature Breakdown Study by Sub-bandgap Photoluminescence
Partha Dutta	Canyon I	Monday	01:30 PM	(Invited) Potential Role of Reduced Gravity for Semimetal-Semiconductor Composite Bulk Crystal Growth and Novel Devices
Partha Dutta	Canyon II & IV	Monday	08:00 AM	Welcome!
Sivasankara Rao Ede	Aster	Monday	02:50 PM	Optimizing Oxygen Reduction Reaction Efficiency through Templated Synthesis and Crystallographic Orientation Control of Transition Metals within Graphitic Nanofibers

Jim Evans	Canyon III	Thursday	04:30 PM	(Invited) Reshaping and diffusion of metallic nanocrystals
Michael Filler	Canyon III	Thursday	11:00 AM	(Invited) Buckets of Transistors: Scalable Nanoelectronic Devices via Bottom-up Crystal Growth and Area-Selective Processes
Vincent Fratello	Canyon II & IV	Monday	02:00 PM	(Invited) Solution Phase Diagram of Lead Zirconate Titanate (PZT) in a High Temperature Solution
Vincent Fratello	Aster	Friday	10:30 AM	(Invited) Crystal Growth of [100] Lead Zirconate Titanate (PZT) Crystals with composition Near the Morphotropic Phase Boundary by High Temperature Solution Growth
Vincent Fratello	Canyon II & IV	Tuesday	03:00 PM	(Invited) Ken Jackson's Life and Work
Alex Galyukov	Canyon I	Thursday	10:30 AM	(Invited) Advancements in Numerical Modeling of Epitaxy of Electronic Materials
Wei Gao	Canyon II & IV	Monday	02:30 PM	Vertical gradient freeze growth of 8 inch diameter semiconducting GaAs
Alexander Goldstone	Aster	Monday	02:00 PM	(Invited) MBE growth of single and polycrystalline CdTe and CdSeTe for photovoltaic applications
Mark Goorsky	Canyon I	Wednesday	01:30 PM	(Invited) Engineered Substrates: Understanding structure and defects through x-ray and electron-based characterization techniques
Mark Goorsky	Canyon II & IV	Monday	03:30 PM	(Invited) Defect Evolution and Mg Segregation in implanted GaN using Ultra-High-Pressure Annealing
Venkatraman Gopalan	Canyon II & IV	Thursday	03:30 PM	(Invited) Design and Discovery of Superior Nonlinear Optical Crystals
Laurie Gower	Aster	Wednesday	04:00 PM	(Invited) TBD
Christopher Grainger	Aster	Monday	10:30 AM	(Invited) Extreme Helical Morphology Exhibited by Iodinated Phenanthroline Crystals
Andrew Graves	Canyon III	Monday	02:30 PM	Epitaxial Growth of Transition Metal Dichalcogenide Monolayers by MOCVD for Large Area Device Applications
Shekhar Guha	Canyon II & IV	Thursday	05:00 PM	(Invited) Anisotropic thermal properties of CdSiP2 crystals
Shekhar Guha	Canyon I	Wednesday	04:00 PM	(Invited) Measurement of temperature-dependent refractive indices and absorption coefficients of ZnSe and ZnTe
James Gupta	Canyon III	Wednesday	05:00 PM	Real-time, In-situ Flux Monitoring: A Revolutionary New Development in Solid-Source Molecular Beam Epitaxy
Jung Han	Canyon II & IV	Monday	09:15 AM	Frontiers in Selective Area Growth, Etching, and Doping of GaN by OMVPE
Rastgo Hawrami	Aster	Tuesday	10:30 AM	(Invited) Intrinsic TI-based Halide Scintillators for Particle Detectors
Alison Haymaker	Aster	Wednesday	04:30 PM	Tatumella morbirosei: A Study of Cyanophycin Synthetase and Cyanophycin

Michael Heuken	Canyon I	Monday	08:40 PM	In-situ Reflectometry for Controlling Synthesis of 2D Materials and Heterostructures during MOCVD
Christopher Hinkle	Canyon III	Tuesday	08:00 PM	(Invited) New Functional Heterostructures Through Low-Temperature Growth of van der Waals Materials
Shanshan Hu	Canyon I	Friday	11:50 AM	Investigation of defect formation at the early stage of PVT-grown 4H-SiC crystals
XianRong Huang	Canyon I	Wednesday	02:30 PM	(Invited) The comprehensive synchrotron topography and rocking curve imaging capabilities at the Advanced Photon Source
Luiz Jacobsohn	Aster	Thursday	10:30 AM	(Invited) The Luminescence of Aluminate Spinels: The Role of Defects and Impurities
Jani Jesenovec	Canyon II & IV	Monday	02:50 PM	Controlling Morphology of NiSb Needles in InSb through Low Temperature Gradient Horizontal Gradient Freeze
Xiaoning Jiang	Aster	Friday	08:00 AM	(Invited) Alternating current poled relaxor-PbTiO3 single crystals for ultrasound transducers
Biao Jin	Aster	Tuesday	04:50 PM	Biomimetic Control of Sequence-Defined Peptoids over Ag Nanocrystal Formation and Anisotropic Self-Assembly
Derk Joester	Aster	Tuesday	03:30 PM	(Invited) Nucleation Kinetics of Amorphous Carbonates in Confinement
Guangxu Ju	Canyon I	Tuesday	03:00 PM	(Invited) Revealing the Alternating Step Kinetics during Nitride Growth by OMVPE
Kei Kamada	Arizona Foyer	Monday	05:30 PM	(Poster) Development of Ce doped LiGdCl4/LiCl eutectic as a high concentration 6Li contening thermal neutron scintillator
Sakiko Kawanishi	Canyon I	Wednesday	05:00 PM	In-situ observation of 4H-SiC{0001} dissolution into molten alloy at 1500 K
Joel Kearns	Canyon II & IV	Wednesday	04:30 PM	Attributes of heavily phosphorus-doped dislocation free silicon crystals for PowerMOS device substrates
Joel Kearns	Aster	Monday	02:30 PM	Growth twins in gallium doped, dislocated single crystal silicon from NeoGrowth crystallization method
Joseph Kolis	Canyon II & IV	Thursday	11:30 AM	(Invited) Hydrothermal Growth of Magnetically Frustrated Crystals: Lanthanide Stannate Pyrochlores as a Prototype
Jimmy Kotsakidis	Canyon III	Monday	01:30 PM	(Invited) Investigating the Magnetotransport Properties of Hydrogen and Magnesium Intercalated Graphene on Silicon Carbide.
Jan Kovar	Canyon II & IV	Monday	11:00 AM	Experience-based Feedforward control of Czochralski growth process using data processing.
Sriram Krishnamoorthy	Canyon I	Friday	09:00 AM	Epitaxy and Engineering of beta-Ga2O3 Devices for High-Voltage Applications
Prashant Kumar	Aster	Monday	11:00 AM	(Invited) Bowties vs Mantis Shrimp. Who can rotate the polarization of light better?
Akito Kuramata	Canyon I	Friday	08:00 AM	(Invited) Gallium Oxide Bulk Crystal and Substrates Technology.

Shoufeng Lan	Canyon III	Monday	04:00 PM	(Invited) Reciprocal Quantum Electrodynamics for Two-Dimensional Materials
Jacob Leach	Canyon I	Tuesday	10:30 AM	(Invited) GaN on GaN Epigrowth Using Chemically Pure Hydride Vapor Phase Epitaxy (HVPE)
Seunghyun Lee	Canyon I	Thursday	03:30 PM	(Invited) Extremely low excess-noise and high gain AlxGa1-xAsSb avalanche photodiodes lattice matched to InP substrates
Stephanie Lee	Aster	Monday	11:30 AM	(Invited) Twisted Organic Semiconductor Crystals
Robert Leonard	Canyon I	Friday	10:30 AM	(Invited) Large Diameter 4H-SiC Growth and Defect Characterization Methods
Fei Li	Aster	Thursday	04:30 PM	(Invited) Textured BiScO3-PbTiO3 Piezoelectric Ceramics with both High Electromechanical Coupling Factor and High Curie Temperature
Jinglei Li	Aster	Friday	11:30 AM	(Invited) Lead zirconate titanate ceramics with aligned crystallite grains
Qiang Li	Canyon III	Wednesday	04:00 PM	(Invited) MOCVD growth of InAs/InP quantum dots for C-band to near 2 Âμm emission
Adam Lindsey	Canyon II & IV	Monday	11:40 AM	Bulk Crystal Growth of Yb3Ga5O12 and GdLiF4 for Adiabatic Demagnetization Refrigeration Devices
Yafei Liu	Arizona Foyer	Monday	05:30 PM	(Poster) Characterization of Growth Sectors in Gallium Nitride Substrate Wafers
Cheng Liu	Canyon III	Thursday	11:30 AM	Nanoscale selective area growth of ultra-high density InGaN/GaN QDs for visible emission patterned by diblock copolymer
Jun Lou	Canyon III	Monday	11:30 AM	(Invited) Towards Controlled Synthesis and Scalable Production of 2D Crystals
James Loveless	Canyon I	Tuesday	03:30 PM	Micro-Electroluminescence and -Photoluminescence of Hexagonal Hillocks in UVC LEDs
Tony Low	Canyon III	Monday	08:30 PM	(Invited) Novel plasmonic effects in 2D materials
Jun Luo	Aster	Friday	12:00 PM	(Invited) Development of Doped Relaxor-PT Ferroelectric Crystals at TRS
Robert Macfarlane	Canyon III	Thursday	01:30 PM	(Invited) Nanoparticle Assembly into Ordered Superlattices: When and Why these 'Artificial Atoms' Break Conventional Rules for Crystallization
lan Manning	Canyon II & IV	Thursday	01:30 PM	(Invited) Development and scale-up of n-type conductive SiC for power electronics applications
Justin Mark	Canyon II & IV	Thursday	02:00 PM	(Invited) Manufacturing 2-inch AIN and beyond: the road to 4-inch AIN substrates
Hiroki Matsuo	Aster	Friday	09:00 AM	(Invited) Ferroelectric BiFeO3-based epitaxial thin films with engineered domain structures for photovoltaic applications
Brelon May	Canyon I	Tuesday	05:00 PM	Molecular Beam Epitaxy of Binary and Ternary Manganese and Chromium Nitrides

John McCloy	Canyon II & IV	Monday	10:30 AM	(Invited) Bulk Crystal Growth and Opto-electronic Characterization of β-Ga2O3
Stephen McDonnell	Canyon III	Tuesday	05:00 PM	(Invited) Synthesis of Transition Metal Dichalcogenides on oxide surfaces
Peter Menge	Aster	Thursday	11:00 AM	(Invited) Recent developments in Scintillator Co-doping at Luxium Solutions
Richard Meyer	Aster	Thursday	03:30 PM	(Invited) Process/Property Relationships of Textured Piezoelectric Ceramics for Acoustic Applications
Moira K. Miller	Canyon I	Tuesday	11:20 AM	Optimization of ZnGeN2/GaN Quantum Wells for Green LEDs
Oussama Moutanabbir	Canyon II & IV	Tuesday	11:20 AM	(Invited) Growth of metastable (Si)GeSn semiconductors
Peter Muzykov	Canyon I	Friday	11:30 AM	Evaluation of thermal stress distribution in off-axis grown SiC crystals
Rachael Myers-Ward	Canyon III	Monday	03:30 PM	(Invited) Epitaxial Graphene for Sensing Applications
Sina Najmaei	Canyon III	Tuesday	10:30 AM	(Invited) 2D Materials Electronic and Optoelectronic Device Applications
Brent Nannenga	Aster	Tuesday	03:00 PM	(Invited) Biomolecular and materials structure determination by cryo-electron microscopy and microcrystal electron diffraction
Greg Olsen	Canyon II & IV	Tuesday	01:30 PM	TBD
Ryuji Oshima	Aster	Monday	04:00 PM	(Invited) Overview of hydride vapor phase epitaxy development for affordable III-V solar cells at AIST
Aleksandar Ostrogorsky	Canyon I	Monday	04:20 PM	Crystal Growth in the SUBSA furnace in MSG: 2002 to 2022
Aleksander Ostrogorsky	Canyon II & IV	Tuesday	08:30 AM	Bridgman Crystal Growth on Earth and in Microgravity
Divya Panchanathan	Canyon I	Monday	04:00 PM	Commercial Space Platform for Crystal Growth
Amish Patel	Canyon III	Thursday	03:30 PM	(Invited) Molecular Insights into the Interactions between Antifreeze Proteins and Ice
Yan Peng	Canyon I	Friday	11:00 AM	(Invited) The research and industrialization of SiC substrate in China
Daniel Pennachio	Canyon III	Monday	10:30 AM	(Invited) Novel Graphene and SiC Epitaxy to Enable Film Transfer
Kimberly Pestovich	Aster	Tuesday	11:00 AM	First Bridgman growth of RbSrl3:Eu scintillator for high energy X-ray radiography
Baron Peters	Canyon III	Thursday	04:00 PM	(Invited) Crystal growth impedance from boundary layer transport, conformational interconversion, and dimerization kinetics

Jasnamol Pezhumkattil Palakkal	Canyon II & IV	Tuesday	11:50 AM	Effect of valence electrons on the core level x-ray photoelectron spectra of 4d transition-metal oxide thin films
Siddha Pimputkar	Canyon I	Tuesday	09:00 PM	Computational Fluid Dynamics Modeling of a Novel High-Pressure Spatial Chemical Vapor Deposition Reactor (HPS-CVD) Design for Growth of Indium-Containing Nitrides
Nikhil Pokharel	Canyon I	Monday	08:20 PM	Optical and Structural Characteristics of ~1.65um-emitting Quantum Dots Grown by Selective Area Epitaxy
Jan Polak	Canyon II & IV	Monday	11:20 AM	Growth of large diameter yttrium aluminium garnet crystals by Czochralski method
John Prineas	Canyon I	Thursday	02:00 PM	(Invited) Purcell Effect versus Auger Recombination in Variable Thickness Superlattices in Resonant Cavity Mid Infrared LEDs
Cristyan Quiñones	Canyon I	Tuesday	09:40 PM	Quasi Vertical Schottky Barrier Diodes on Bulk AIN Substrates
Siddharth Rajan	Canyon I	Friday	08:30 AM	(Invited) Materials and Device Engineering for High-Performance Gallium Oxide Electronics
Apparao Rao	Canyon III	Tuesday	03:30 PM	(Invited) Structure-optimized phosphorene for super-stable potassium storage
Shashwat Rathkanthiwar	Canyon I	Tuesday	05:20 PM	Conduction mechanism in Mg-doped compositionally graded AlGaN: the role of polarization field and point defects
Vladimir Riabov	Canyon I	Monday	04:40 PM	Detached Melt and Vapor Growth of Inl in SUBSA hardware
Shirin Riahi	Canyon III	Thursday	02:00 PM	Gallium doped zinc oxide nanowires for quantum information applications: optical characterization of doping
Brooks Tellekamp	Canyon I	Tuesday	08:40 PM	Lattice matched virtual substrates for Al-X-N epitaxy
Harold Robinson	Aster	Thursday	02:00 PM	(Invited) A Review of Single Crystal Underwater Transducers
Alexana Roshko	Canyon II & IV	Monday	04:40 PM	Defect Elimination in N-Polar GaN Nanostructures on Si
Arindam Roy	Arizona Foyer	Monday	05:30 PM	(Poster) Growth and characterization of metal derivative of 1,4-Diazobicyclo [2.2.2] octane (DABCO) for non-linear optical applications.
Daniel Rutstrom	Aster	Thursday	11:30 AM	Discovery and Scale Up of New Ultrafast Chloride Scintillators
Jae-Hyun Ryou	Canyon II & IV	Monday	04:20 PM	Single-Crystalline Layer-Transferred III-N Films for Flexible Piezoelectric Sensors in Extreme Environment Applications
Jae-Hyun Ryou	Canyon I	Tuesday	11:00 AM	Piezoelectric Single-Crystalline Flexible GaN Thin Film for Stress Hormone Detection from Sweat
Kavitha S	Arizona Foyer	Monday	05:30 PM	(Poster) Investigation on structural, elemental, spectral, thermal, mechanical, linear, and nonlinear optical nature of Rubidium hydrogen succinate dihydrate metal-organic single crystals
Theresa Saenz	Canyon I	Monday	11:00 AM	(Invited) GaAs solar cells on V-groove Si substrates

Suja Elizabeth Saji	Canyon I	Wednesday	02:00 PM	(Invited) Growth and characterization of pure and substituted rare-earth orthoferrite single crystals
Leo Schowalter	Canyon II & IV	Tuesday	09:15 AM	The development of ultrawide bandgap, pseudomorphic AlGaN semiconductor on native AlN substrates and its potential for opto-electronic and power devices (dedicated to Crystal IS cofounder Glen Slack, 1928-2019)
Kevin Schulte	Aster	Monday	04:30 PM	27% Efficient GaAs Solar Cells Grown on Acoustically Spalled Substrates for Lower Cost III-V Photovoltaics
Peter Schunemann	Canyon II & IV	Thursday	04:00 PM	Ternary chalcopyrite semiconductors for mid-IR laser applications
Peter Schunemann	Canyon II & IV	Thursday	04:20 PM	Growth of BaGa4S7 and BaGa4Se7: new broad-band nonlinear crystals for the mid-infrared
Peter Schunemann	Canyon III	Wednesday	02:15 PM	(Invited) All-epitaxial growth of orientation-patterned GaAs and GaP engineered nonlinear optical crystals
Sagnik Sen	Aster	Wednesday	04:50 PM	SINGLE PARTICLE CRYO-EM STRUCTURE OF FERRITIN BIOMINERALIZATION SHOWING THE PROTEIN-NANOPARTICLE COMPLEX
Chenyang Shi	Aster	Tuesday	05:10 PM	Multiphase silk assembly for two-dimensional composite
Frank Siebke	Aster	Monday	01:30 PM	(Invited) Green Solar Wafers for High-Efficiency Solar Cells Produced by Epitaxy
Narsingh Singh	Canyon II & IV	Thursday	02:30 PM	(Invited) Optical emission characteristics of PVT grown doped ZnSe crystals in near IR wavelength region
Narsingh Singh	Canyon II & IV	Tuesday	05:00 PM	(Invited) Evolution of Jackson-Hunt Diffusion theory and transition into 3D-dendritic morphology: An Overview
Narsingh Bahadur Singh	Canyon I	Thursday	11:00 AM	(Invited) Growth of 2H-SiC pure hexagonal polytype by using nucleating agents
Talid Sinno	Canyon II & IV	Wednesday	04:00 PM	(Invited) Impact of configurational entropy on point defect thermodynamics in silicon
Talid Sinno	Canyon III	Thursday	05:30 PM	Computational Study of Non-Classical Homogeneous Crystallization in Liquid Si
Zlatko Sitar	Canyon II & IV	Monday	08:30 AM	Unlocking the AlN-based technology through crystal growth and epitaxy
Trevor Smith	Canyon I	Monday	08:00 PM	Ga(As,P) OMVPE on Si substrates employing surfactant Sb and Ge ion implantation
Michael Snure	Canyon III	Monday	02:50 PM	Growth of BN dielectric layer on GaN by metal organic chemical vapor deposition
Michael Snure	Canyon II & IV	Monday	04:00 PM	Stress induced van der Waals lift-off of 4-inch GaN grown on two-dimensional BN by metal organic chemical vapor deposition
Alexander Soibel	Canyon I	Thursday	01:30 PM	(Invited) Development of mid- and long-wavelength infrared detectors and focal plane arrays in JPL
Anthony SpringThorpe	Canyon I	Monday	11:30 AM	RELIABLE BURIED HETEROSTRUCTURE LASER via AN MOCVD IN-SITU ETCH PROCESS

Gregory Brian Stephenson	Canyon II & IV	Tuesday	04:30 PM	(Invited) BCF Analysis of Azimuth Dependence of Step Dynamics
Chao Hsuan (Joseph) Sung	Canyon II & IV	Tuesday	11:00 AM	Polymer Assisted Growth of Metal Nanoparticles for Sensing Applications
Maria Sushko	Canyon II & IV	Wednesday	04:50 PM	Crystallization pathways and interfacial drivers for the formation of hierarchical architectures
Michael Susner	Canyon II & IV	Thursday	10:30 AM	(Invited) Synthesis and Characterization of Novel Metal Thiophosphate Materials
Eli Sutter	Canyon III	Tuesday	11:00 AM	(Invited) Growth and Emerging Functionality of van der Waals Crystals and Heterostructures
Peter Sutter	Canyon III	Tuesday	08:30 PM	Growth and Emerging Functionality of van der Waals Crystals and Heterostructures
Johannes Svensson	Canyon I	Monday	10:30 AM	(Invited) Template-Assisted Selective Epitaxy of InAs on W metal films
Kazuya Takahashi	Canyon II & IV	Monday	01:30 PM	(Invited) Crystal growth and characterization of large Ca0.582Sr0.418F2 single crystal by Czochralski method using cone die
Rylan Terry	Canyon II & IV	Wednesday	03:00 PM	Crystal Growth, Structure and Magnetism of Transition Metal "Hobby†Crystals
Jifa Tian	Canyon III	Tuesday	04:30 PM	(Invited) Electrical Transport and Phase Modulation in Two-Dimensional Topological Superconductors
Jian Tian	Aster	Thursday	01:30 PM	(Invited) Development in Crystal Growth of PMN-PT Based Single Crystals
Sefaattin (Seth) Tongay	Canyon III	Monday	04:30 PM	(Invited) The synthesis and engineering of two-dimensional Janus quantum layers
Joshua Tower	Canyon II & IV	Thursday	11:00 AM	(Invited) Low-Background Crystals for Rare Event Searches in Nuclear and High Energy Physics
Sudhir Trivedi	Canyon II & IV	Friday	08:00 AM	(Invited) Cd1-x-yMgxZnyTe, a New Alternative High-Performance Radiation Detector Material
Amalthea Trobasre	Arizona Foyer	Monday	05:30 PM	(Poster) Optical characteristics of multifunctional heavy metal based multifunctional materials
Logan Tsosie	Aster	Wednesday	05:10 PM	Delineating the Roles of Casein at the Interface in Enzyme Induced Carbonate Precipitation (EICP) with Highly-Resolved Spatial and Temporal Methods
Moneesh Upmanyu	Canyon II & IV	Wednesday	01:30 PM	(Invited) Stress modulation via oscillations in emergent grain boundary phases during growth of polycrystalline thin films
Edgar van Loef	Canyon II & IV	Friday	08:50 AM	Crystal Growth, Density Functional Theory, and Scintillation Properties of TISr2Cl5 and Tl2Sr2Br5
Peter Vekilov	Canyon II & IV	Wednesday	02:15 PM	(Invited) Concentration-driven transition between classical and nonclassical modes in organic crystallization
Peter Vekilov	Canyon I	Monday	03:30 PM	(Invited) Solution convection and the nucleation precursors in protein condensation.

Martin Volz	Aster	Tuesday	11:20 AM	Thermophysical Property Measurements of Indium Iodide Crystals
Kerstin Volz	Canyon I	Monday	09:00 PM	Atomically-resolved structure and composition at III-V device heterointerfaces grown by MOVPE
Satoshi Wada	Aster	Friday	08:30 AM	(Invited) AC Poling Treatment over Tc in Grain-oriented BT-BNT Piezoceramics
Nicole Wagner	Canyon I	Monday	02:00 PM	Characterization of Protein-based Artificial Retina Thin Films Produced via Layer-by-Layer Assembly on the International Space Station
Peng Wang	Aster	Tuesday	11:40 AM	Using In-situ Sublimation Methods in the Growth of Halide Perovskite Single Crystal Semiconductors
Guojian Wang	Aster	Friday	09:30 AM	(Invited) Growth and characterization of PMN-PT crystals by vertical gradient freeze (VGF) technology
Ting Wang	Canyon III	Wednesday	04:30 PM	(Invited) Monolithically Integrated III-V Lasers for Silicon Photonics
Hayato Watanabe	Arizona Foyer	Monday	05:30 PM	(Poster) Investigation of non-destructive and non-contact electrical characterization of GaN thin film on ScAIMgO4 substrate using THz-TDSE with characteristic impedance analytical model
Kimberly Weirich	Aster	Wednesday	01:30 PM	(Invited) TBD
Kai Xiao	Canyon III	Monday	02:00 PM	(Invited) Van der Waals epitaxial growth of 2D materials and heterostructures
Jun Xiao	Canyon III	Monday	08:00 PM	(Invited) Layered topological semimetals for novel high-performance electronics and THz optoelectronics
Shining Xu	Canyon I	Monday	09:20 PM	~ 8.1 Î⅓m InP-based quantum cascade lasers grown on Si via OMVPE
Sakshi Yadav Schmid	Aster	Wednesday	03:00 PM	Designed Interfaces Between Proteins and Inorganic Crystals for Templated Assembly and Co-Assembly
Yongke Yan	Aster	Thursday	04:00 PM	(Invited) Templated Grain Growth of High Performance Textured Piezoelectric Ceramics
Jie Yao	Canyon III	Monday	05:00 PM	(Invited) Towards novel morphologies of 2D materials: intercalation and twists
Zuo-Guang Ye	Aster	Thursday	05:00 PM	(Invited) Synthesis and Characterization of High-TC Piezo-/Ferroelectric Single Crystals Based on Bismuth Scandate
Gen Yin	Canyon III	Monday	11:00 AM	(Invited) Electric and spin Hall transition in monolayer Fe3GeTe2
Takeshi Yoshikawa	Canyon I	Wednesday	03:00 PM	Step-bunching on 4H-SiC (000-1) in Si based solutions at 1873 K during interface reconstruction
Haitao Yu	Aster	Wednesday	02:15 PM	Biologically Inspired Synthesis of Metal Oxide Particles with Varied Morphology and Orientation
Kevin Zawilski	Canyon II & IV	Thursday	04:40 PM	Absorption and Defects Related to High Average Power Operation of CdSiP2 Crystals

Yong-Hang Zhang	Canyon I	Thursday	04:30 PM	(Invited) InAs/InAsSb type-II superlattice and its applications in devices
Jingze Zhao	Canyon I	Thursday	02:30 PM	Barrier heterostructures with bulk InAsSb absorbers for high operating temperature long-wave infrared sensors
Jingze Zhao	Canyon I	Thursday	05:00 PM	Long-wave infrared beam steering with InAsSb-based plasmonic phased arrays
Jingze Zhao	Canyon I	Monday	09:40 PM	Impact of tellurium doping on minority carrier lifetime in heterostructures with bulk In(Ga)AsSb absorbers
Jingze Zhao	Aster	Monday	04:50 PM	GaAs/AlGaAs Photodetector Arrays for Soft X-ray Beam Position Monitoring